YJ Planar Schottky Barrier Diode Die Specification

150V 10A, 87mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB087H150AS-280A

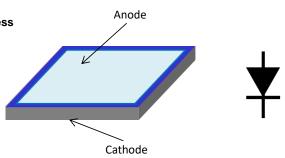
Main Products Characterstics

• Average forward current: IF(AV) = 10 A

• Maximum operating junction temperature: Tj = 175 °C

• ESD rating: >2KV, per IEC61000-4-2 (Contact Discharge)

• Top metal: Al



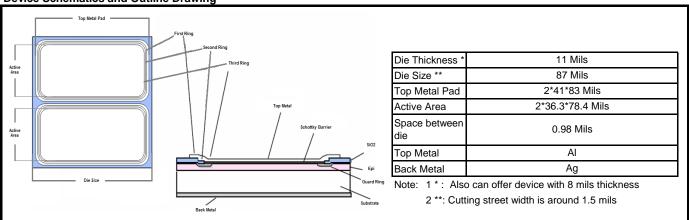
Maximum Ratings

Parameter	Symbol	Rating			
Repetitive peak reverse voltage	V_{RRM}	150 V			
Average forward current	$I_{F(AV)}$	10 A			
Non-repetitive peak surge current (tp = 8.3 ms, halfwave, 1 cycle)	I _{FSM}	120 A			
Storage temperature range	T_{stg}	-50 to +175 °C			
Maximum operating junction temperature	T _j	175 °C			

Static Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Value		
		Spec	Typical	
Reverse breakdown voltage $I_R = 1 \text{mA}$	V_{BR}	155 V	170V	
Maximum forward voltage drop				
I _F = 10A	V_{F}	0.9V	0.82V	
Pulse Test: tp = 300 μ s, $\delta \leqslant 2\%$				
Maximum reverse current V _R = V _{RRM}		3uA	0.3uA	
Pulse Test: tp = 300 μ s, $\delta \le 2\%$	I _R	Jun	0.JuA	

Device Schematics and Outline Drawing



Important Notice

Specification apply to die only. Actual performance may degrade when assembled.

Yangjie Electronics does not guarantee device performance after assembly.

All operating parameters must be validated for each customer application by customer technical experts.

Data sheet information is subjected to change without notice.

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Recommended Storage Environment:

Store in original container, in dessicated nitrogen, with no contamination.

Shelf life for parts stored in above condition is 2 years.

If the storage is done in normal atmosphere shelf life is reduced to 6 months.

扬州扬杰电子科技股份有限公司

传真: 0514-80980189

Yangzhou Yangjie Electronics Technology Co.,Ltd.

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电话: 0514-80982389